NSN 5962-01-121-2190

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View Online at https://aerobasegroup.com/nsn/5962-01-121-2190

Body Length:
0.870 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.140 inches and 0.180 inches
Maximum Power Dissipation Rating:
333.0 milliwatts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
6625-01-076-1763 fscm 52542
Features Provided:
Monolithic and positive outputs and programmable and w/decoded output and w/open collector
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Terminal Surface Treatment:
Silver
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Precious Material And Location:
Terminal surface silver
Precious Material:
Silver
Test Data Document:
52542-055123 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

16 printed circuit

Terminal Type And Quantity:

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•	n	0 1	•	12	e:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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